NSN 5961-01-336-1797

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-336-1797 **Inclosure Material:** Ceramic and metal **Overall Length:** 27.000 inches **Overall Height:** 21.000 inches **Overall Width:** 27.000 inches **Function For Which Designed:** Switching **Component Name And Quantity:** 3 semiconductor device diode and 3 semiconductor device thyristor **Mounting Method:** Press fit **Semiconductor Material:** Silicon 2nd semiconductor device diode Voltage Rating In Volts Per Characteristic: 480.0 regulator voltage 2nd semiconductor device diode **Current Rating Per Characteristic:** 60.00 amperes forward current, average absolute 2nd semiconductor device diode **Power Rating Per Characteristic:** 41.5 milliwatts small-signal input power, common-collector preset 2nd semiconductor device diode **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No